



ST1802FX

HIGH VOLTAGE FAST - SWITCHING NPN POWER TRANSISTOR

Features

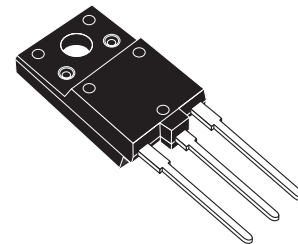
- NEW SERIES, ENHANCED PERFORMANCE
- FULLY INSULATED POWER PACKAGE (U.L. COMPLIANT) FOR EASY MOUNTING
- HIGH VOLTAGE CAPABILITY (>1500V)
- HIGH SWITCHING SPEED
- TIGHTER h_{FE} CONTROL
- IMPROVED RUGGEDNESS
- IN COMPLIANCE WITH THE 2002/93/EC EUROPEAN DIRECTIVE

Applications

- HORIZONTAL DEFLECTION OUTPUT FOR COLOR TV UP TO 29-INCHES

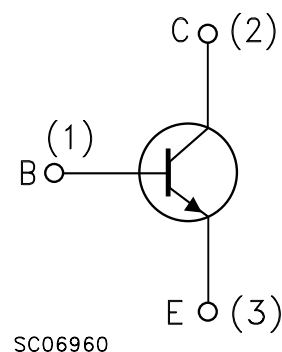
Description

The ST1802FX is manufactured using new Diffused Collector Technology for more stable operation Vs base drive circuit variations resulting in very low worst case dissipation.



ISOWATT218FX

Internal Schematic Diagram



Order codes

Part Number	Marking	Package	Packing
ST1802FX	1802FX	ISOWATT218FX	TUBE

1 Electrical Ratings

Table 1. Absolute Maximum Rating

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage ($I_E = 0$)	1500	V
V_{CEO}	Collector-Emitter Voltage ($I_B = 0$)	600	V
V_{EBO}	Collector-Base Voltage ($I_C = 0$)	7	V
I_C	Collector Current	10	A
I_{CM}	Collector Peak Current ($t_P < 5ms$)	15	A
I_B	Base Current	4	A
P_{TOT}	Total dissipation at $T_C = 25^\circ C$	60	W
V_{isol}	Insulation Withstand Voltage (RMS) from all three Leads to External Heatsink	2500	V
T_{stg}	Storage Temperature	-65 to 150 150	$^\circ C$
T_J	Max. Operating Junction Temperature		

Table 2. Thermal Data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal Resistance Junction-Case Max	2.1	$^\circ C/W$

2 Electrical Characteristics

($T_{CASE} = 25^{\circ}\text{C}$; unless otherwise specified)

Table 3. Electrical Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector Cut-off Current ($V_{BE} = 0$)	$V_{CE} = 1500\text{V}$			1	mA
		$V_{CE} = 1500\text{V}$ $T_C = 125^{\circ}\text{C}$			2	mA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{EB} = 7\text{V}$			1	mA
$V_{CEO(sus)}$ <i>Note 1</i>	Collector-Emitter Sustaining Voltage ($I_B = 0$)	$I_C = 700\text{ mA}$ $L = 25\text{ mH}$	600			V
$V_{CE(sat)}$ <i>Note 1</i>	Collector-Emitter Saturation Voltage	$I_C = 4\text{ A}$ $I_B = 0.8\text{ A}$			5	V
		$I_C = 4\text{ A}$ $I_B = 1.2\text{ A}$			1.5	V
$V_{BE(sat)}$ <i>Note 1</i>	Base-Emitter Saturation Voltage	$I_C = 4.5\text{ A}$ $I_B = 1\text{ A}$			1.2	V
h_{FE}	DC Current Gain	$I_C = 1\text{ A}$ $V_{CE} = 5\text{ V}$		25		
		$I_C = 5\text{ A}$ $V_{CE} = 1\text{ V}$		4.5		
		$I_C = 5\text{ A}$ $V_{CE} = 5\text{ V}$	4		9	
t_s	INDUCTIVE LOAD Storage Time	$I_C = 4\text{ A}$ $f_h = 16\text{ KHz}$		2.6	4	μs
t_f	Fall Time	$I_{B(on)(END)} = 850\text{ mA}$ $V_{BB(off)} = -2.5\text{ V}$ $L_B = 4.5\mu\text{H}$		0.2	0.6	μs

1 Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$.

2.1 Electrical Characteristics (curves)

Figure 1. Safe Operating Area

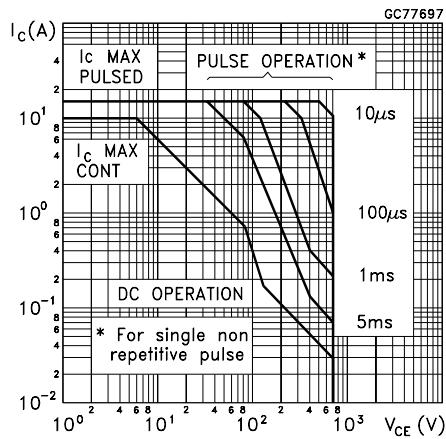


Figure 2. Thermal Impedance

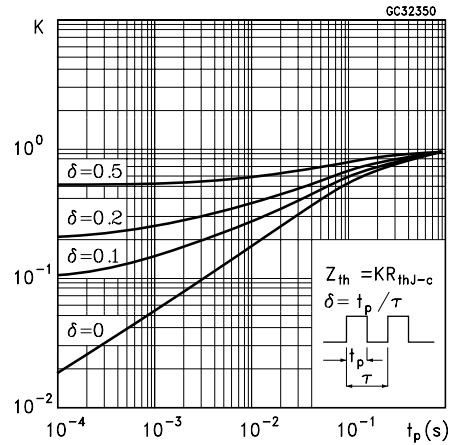


Figure 3. Collector-emitter saturation voltage

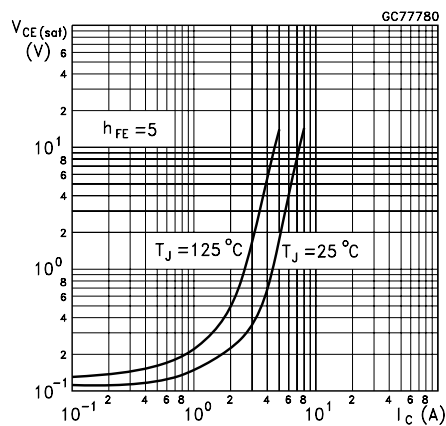


Figure 5. DC current gain

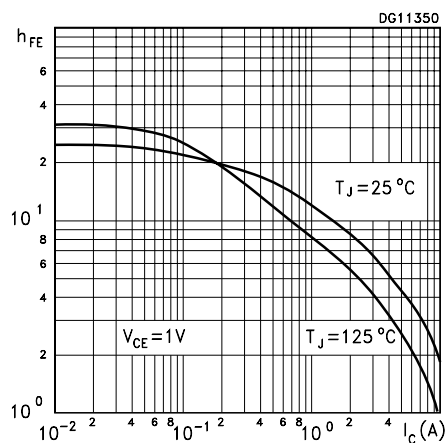


Figure 4. Base-emitter saturation voltage

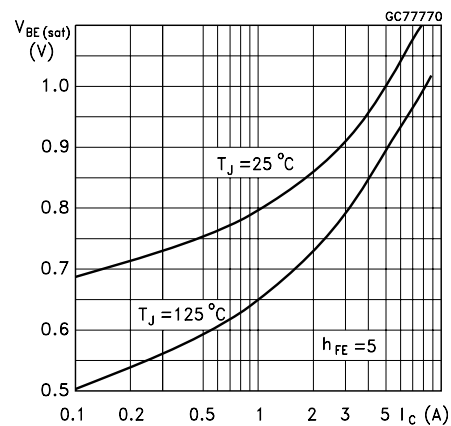


Figure 6. DC current gain

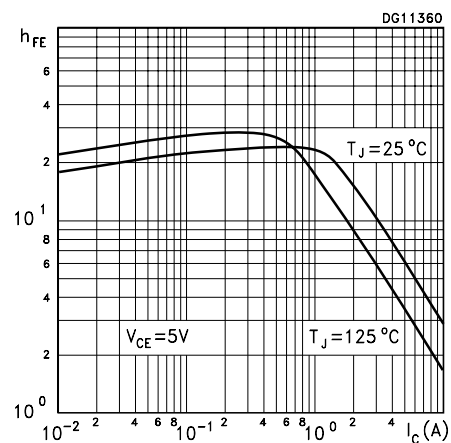


Figure 7. Power losses at 16KHz

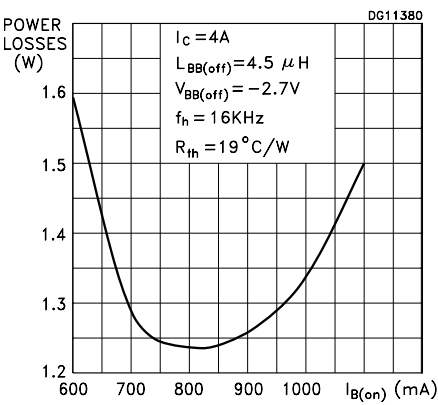


Figure 8. Switching time inductive load

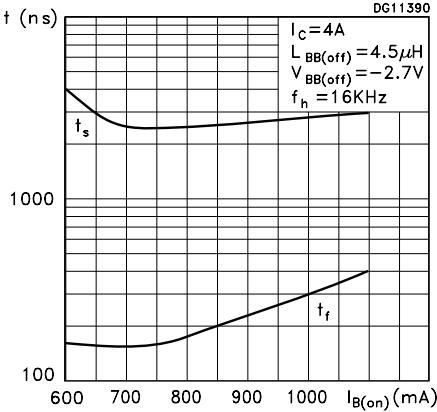
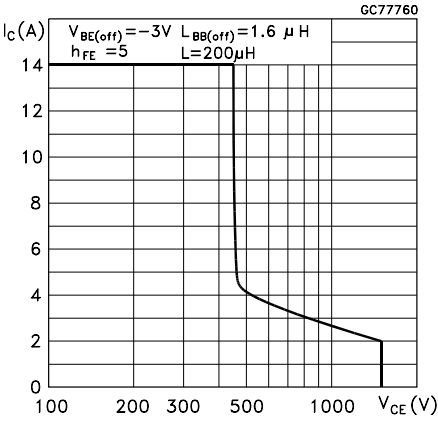
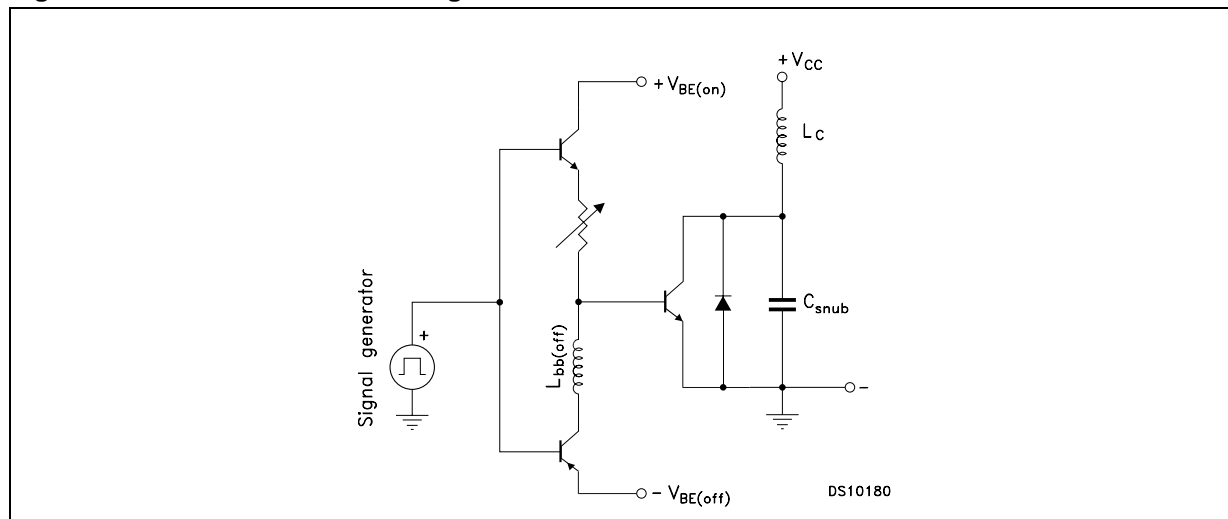


Figure 9. Reverse biased area



3 Test Circuit

Figure 10. Inductive load switching test circuit

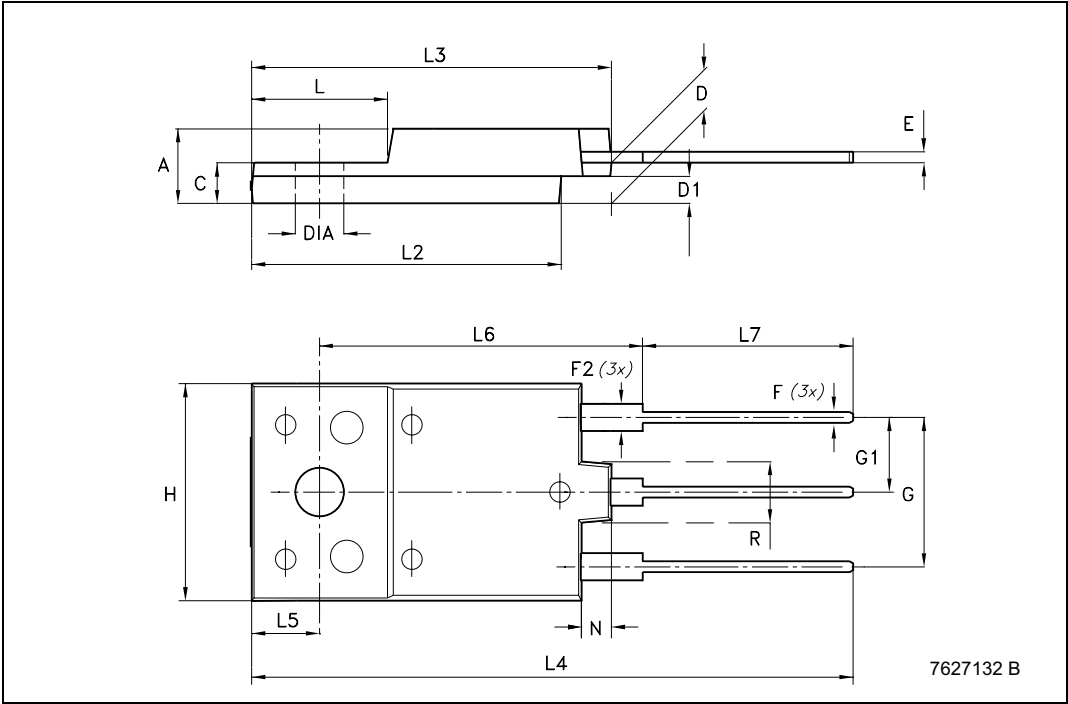


4 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

ISOWATT218FX MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A	5.30		5.70
C	2.80		3.20
D	3.10		3.50
D1	1.80		2.20
E	0.80		1.10
F	0.65		0.95
F2	1.80		2.20
G	10.30		11.50
G1		5.45	
H	15.30		15.70
L	9		10.20
L2	22.80		23.20
L3	26.30		26.70
L4	43.20		44.40
L5	4.30		4.70
L6	24.30		24.70
L7	14.60		15
N	1.80		2.20
R	3.80		4.20
Dia	3.40		3.80



5 Revision History

Date	Revision	Changes
18-Oct-2005	1	First release

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